RFM®

RO2101

433.92 MHz SAW Resonator

- *Ideal for 433.92 MHz Transmitters*
- *Very Low Series Resistance*
- *Quartz Stability*
- *Rugged, Hermetic, Low-Profile TO39 Case*

The RO2101 is a true one-port, surface-acoustic-wave (SAW) resonator in a low-profile TO39 case. It provides reliable, fundamental-mode, quartz frequency stabilization of fixed-frequency transmitters operating at 433.92 MHz. The RO2101 is designed specifically for remote-control and wireless security transmitters operating in Europe under ETSI I-ETS 300 220 and in Germany under FTZ 17 TR 2100.

TO39-3 Case

Absolute Maximum Ratings

Rating	Value	Units
CW RF Power Dissipation	+0	dBm
DC Voltage Between Any Two Pins	±30	VDC
Case Temperature	-40 to +85	°C

Electrical Characteristics

Characteristic		Sym	Notes	Minimum	Typical	Maximum	Units
Center Frequency (+25 °C)	Absolute Frequency	f_C	2, 3, 4, 5	433.845		433.995	MHz
	Tolerance from 433.920 MHz	Δf_C				±75	kHz
Insertion Loss		IL	2, 5, 6		1.5	2.0	dB
Quality Factor	Unloaded Q	Q_U	5, 6, 7		12,800		
	50 Ω Loaded Q	Q_L			2,000		
Temperature Stability	Turnover Temperature	T_O	6, 7, 8	24	39	54	°C
	Turnover Frequency	f_O			$f_c + 2.7$		kHz
	Frequency Temperature Coefficient	FTC			0.037		ppm/°C^2
Frequency Aging	Absolute Value during the First Year	$|f_A|$	1		≤10		ppm/yr
DC Insulation Resistance between Any Two Pins			5	1.0			MΩ
RF Equivalent RLC Model	Motional Resistance	R_M	5, 7, 9		18	26	Ω
	Motional Inductance	L_M			86.0075		µH
	Motional Capacitance	C_M			1.56417		fF
	Pin 1 to Pin 2 Static Capacitance	C_O	5, 6, 9	1.7	2.0	2.3	pF
	Transducer Static Capacitance	C_P	5, 6, 7, 9		1.7		pF
Test Fixture Shunt Inductance		L_{TEST}	2, 7		78		nH
Lid Symbolization (in Addition to Lot and/or Date Codes)		RFM RO2101					

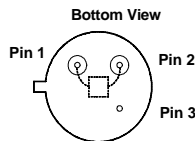**CAUTION: Electrostatic Sensitive Device. Observe precautions for handling.**

Notes:

1. Frequency aging is the change in f_C with time and is specified at +65°C or less. Aging may exceed the specification for prolonged temperatures above +65°C. Typically, aging is greatest the first year after manufacture, decreasing significantly in subsequent years.
2. The center frequency, f_C, is measured at the minimum insertion loss point, IL_{MIN}, with the resonator in the 50 Ω test system (VSWR ≤ 1.2:1). The shunt inductance, L_{TEST}, is tuned for parallel resonance with C_O at f_C. Typically, $f_{OSCILLATOR}$ or $f_{TRANSMITTER}$ is less than the resonator f_C.
3. One or more of the following United States patents apply: 4,454,488 and 4,616,197 and others pending.
4. Typically, equipment designs utilizing this device require emissions testing and government approval, which is the responsibility of the equipment manufacturer.
5. Unless noted otherwise, case temperature T_C = +25°C±2°C.
6. The design, manufacturing process, and specifications of this device are subject to change without notice.

7. Derived mathematically from one or more of the following directly measured parameters: f_C, IL, 3 dB bandwidth, f_C versus T_C, and C_O.
8. Turnover temperature, T_O, is the temperature of maximum (or turnover) frequency, f_O. The nominal frequency at any case temperature, T_C, may be calculated from: $f = f_O [1 - FTC (T_O - T_C)^2]$. Typically, *oscillator* T_O is 20°C less than the specified *resonator* T_O.
9. This equivalent RLC model approximates resonator performance near the resonant frequency and is provided for reference only. The capacitance C_O is the static (nonmotional) capacitance between pin 1 and pin 2 measured at low frequency (10 MHz) with a capacitance meter. The measurement includes case parasitic capacitance with a floating case. For usual grounded case applications (with ground connected to either pin 1 or pin 2 and to the case), add approximately 0.25 pF to C_O.
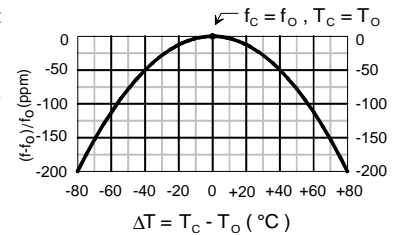
Electrical Connections

This one-port, two-terminal SAW resonator is bidirectional. The terminals are interchangeable with the exception of circuit board layout.

Pin	Connection
1	Terminal 1
2	Terminal 2
3	Case Ground

Bottom View

Pin 1   Pin 2

Pin 3

Typical Test Circuit

The test circuit inductor, L_{TEST}, is tuned to resonate with the static capacitance, C_O at F_C.

Electrical Test:

From 50 Ω Network Analyzer   1   2   From 50 Ω Network Analyzer

3

Power Test:

50Ω Source at F_C — $P_{INCIDENT}$ — Low-Loss Matching Network to 50Ω — $P_{REFLECTED}$

1
3
2

CW RF Power Dissipation = $P_{INCIDENT}$ **-** $P_{REFLECTED}$

Typical Application Circuits

Typical Low-Power Transmitter Application:

Modulation Input — 200kΩ — MPS-H10 — +9VDC — 47

C1 — L1 (Antenna)

1   2

ROXXXX Bottom View — 3 — C2 — RF Bypass

470
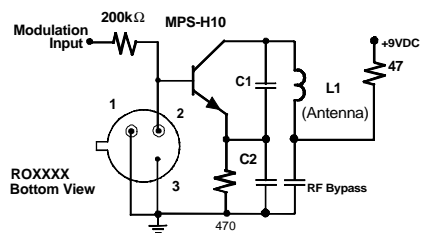
Typical Local Oscillator Application:

+VDC — Output

C1 — L1 — +VDC

1   2

ROXXXX Bottom View — 3 — C2 — RF Bypass

Temperature Characteristics
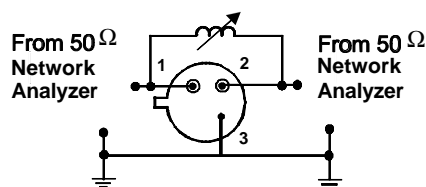
The curve shown on the right accounts for resonator contribution only and does not include oscillator temperature characteristics.
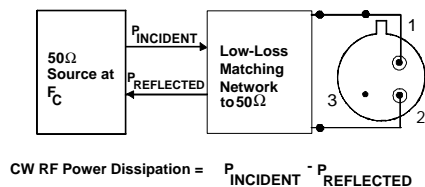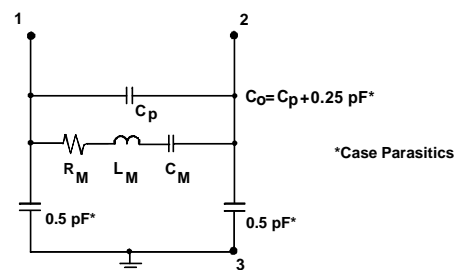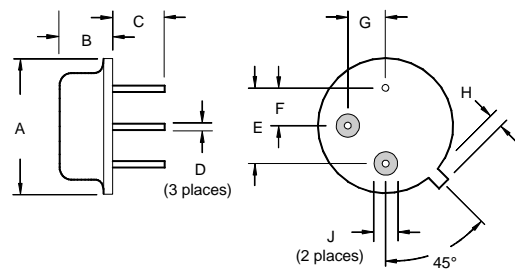
$f_C = f_O$, $T_C = T_O$

(f-f_O)/f_O (ppm)

$\Delta T = T_C - T_O$ (°C)

Equivalent LC Model

The following equivalent LC model is valid near resonance:

1   2

C_P

$C_O = C_P + 0.25$ pF*

R_M L_M C_M

*Case Parasitics

0.5 pF*   0.5 pF*

3

Case Design

B   C

A

D (3 places)

G

E   F

H

J (2 places)   45°

Dimensions	Millimeters		Inches	
	Min	Max	Min	Max
A		9.30		0.366
B		3.18		0.125
C	2.50	3.50	0.098	0.138
D	0.46 Nominal		0.018 Nominal	
E	5.08 Nominal		0.200 Nominal	
F	2.54 Nominal		0.100 Nominal	
G	2.54 Nominal		0.100 Nominal	
H		1.02		0.040
J	1.40		0.055	